

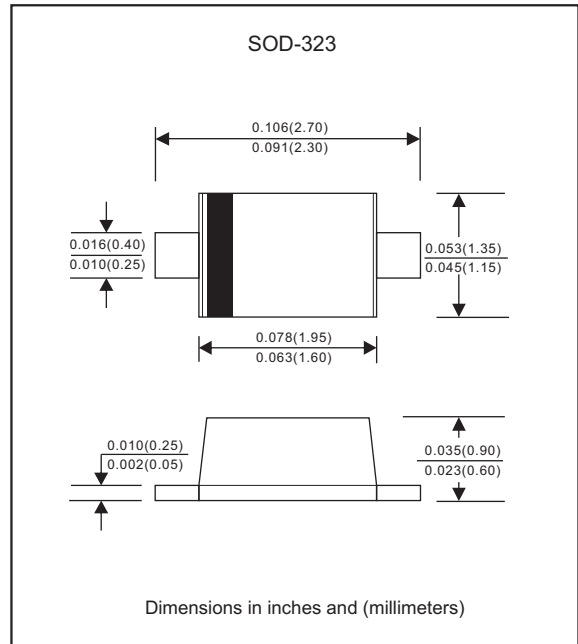
Features

- Small surface mounting type.
- High Speed.
- High reliability with high surge current handling capability.
- We declare that the material of product compliance with RoHS requirements.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts for green partner, exceeds environmental standards of MIL-STD-19500 /228
- Compliant to Halogen-free

Mechanical data

- Epoxy : UL94-V0 rated flame retardant
- Case : Molded plastic, SOD-323
- Terminals :Plated terminals, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any

Package Outline



Maximum ratings (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	Limits	UNIT
Peak reverse voltage	V_{RM}	90	V
DC reverse voltage	V_R	80	V
Peak forward current	I_{FM}	225	mA
Mean rectifying current	I_o	150	mA
Surge current (1s)	I_{surge}	500	mA
Operating junction temperature range	T_J	-55 to +150	$^{\circ}\text{C}$
Storage temperature range	T_{STG}	-55 to +150	$^{\circ}\text{C}$

Electrical Characteristics (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward Voltage ($I_F=100\text{mA}$ dc)	V_F			1.2	V
Reverse Voltage Leakage Current ($V_R=80\text{Vdc}$)	I_R			0.1	μA
Diode Capacitance ($V_R=0.5\text{V}$, $f=1.0\text{MHz}$)	C_T			4.0	pF
Reverse Recover Time ($V_R=6\text{V}$, $I_F=10\text{mA}$, $R_L=100\Omega$)	t_{rr}			4.0	ns

Thermal Characteristics

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Total Device Dissipation FR-5 Board* ¹ , $T_A = 25^{\circ}\text{C}$ Derate Above 25°C	P_D			225 1.8	mW mW/ $^{\circ}\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$			556	$^{\circ}\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate* ² , $T_A = 25^{\circ}\text{C}$ Derate Above 25°C	P_D			300 2.4	mW mW/ $^{\circ}\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$			417	$^{\circ}\text{C}/\text{W}$

1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

Rating and characteristic curves (1SS355)

Fig.1 Forward characteristics

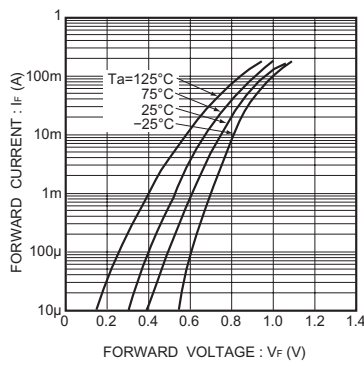


Fig.2 Reverse characteristics

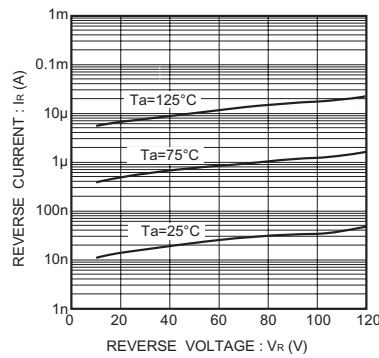


Fig.3 Capacitance between terminals characteristics

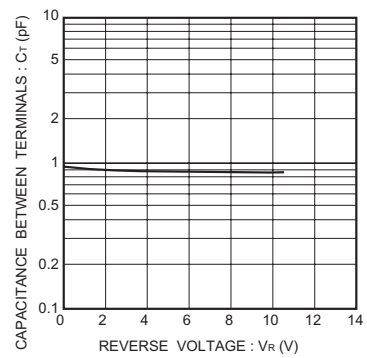


Fig.4 Reverse recovery time characteristics

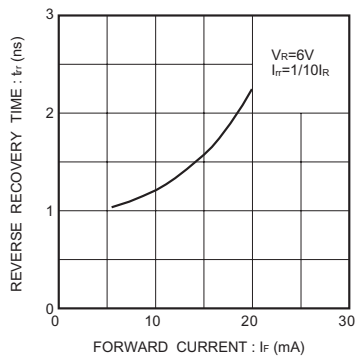


Fig.5 Surge current characteristics

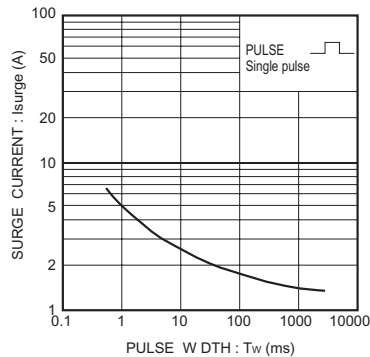
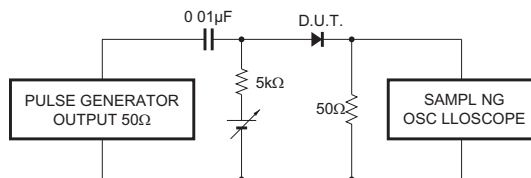




Fig.6 Reverse recovery time (trr) measurement circuit



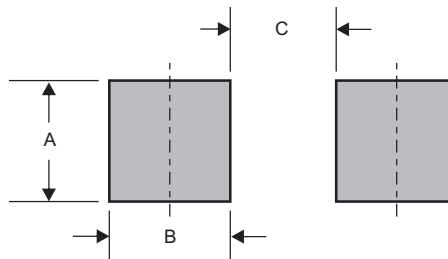
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

Marking

Type number	Marking code
1SS355	S5

Suggested solder pad layout



Dimensions in inches and (millimeters)

PACKAGE	A	B	C
SOD-323	0.032 (0.82)	0.022 (0.56)	0.069 (1.75)

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOD-323	7"	3000	4.0	30,000	195*195*150	178	460*400*420	360,000	14.8

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Diodes - General Purpose, Power, Switching category](#):

Click to view products by [AnBon manufacturer](#):

Other Similar products are found below :

[MCL4151-TR3](#) [MMBD3004S-13-F](#) [RD0306T-H](#) [RD0506LS-SB-1H](#) [RGP30G-E373](#) [DSE010-TR-E](#) [BAQ333-TR](#) [BAQ335-TR](#) [BAQ33-GS18](#) [BAS1602VH6327XT](#) [BAV17-TR](#) [BAV19-TR](#) [BAV301-TR](#) [BAW27-TAP](#) [HSC285TRF-E](#) [NSVBAV23CLT1G](#) [NTE525](#) [1SS181-TP](#) [1SS184-TP](#) [1SS193,LF](#) [1SS193-TP](#) [1SS400CST2RA](#) [SBAV99LT3G](#) [SDAA13](#) [LL4448-GS18](#) [SHN2D02FUTW1T1G](#) [LS4150GS18](#) [LS4151GS08](#) [SMMD7000LT3G](#) [FC903-TR-E](#) [1N4449](#) [1N4934-E3/73](#) [1SS226-TP](#) [APT100DL60HJ](#) [RFUH20TB3S](#) [RGP30G-E354](#) [RGP30M-E3/73](#) [D291S45T](#) [MCL4151-TR](#) [BAS 16-02V H6327](#) [BAS 21U E6327](#) [BAS 28 E6327](#) [BAS33-TAP](#) [BAS 70-02V H6327](#) [BAV300-TR](#) [BAV303-TR3](#) [BAW27-TR](#) [BAW56DWQ-7-F](#) [BAW56M3T5G](#) [BAW75-TAP](#)